

### 1. General description

PNP/PNP matched double transistors in an ultra small DFN1010B-6 (SOT1216) leadless Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: BCM847QAS

### 2. Features and benefits

- Reduces component count
- Reduces pick and place costs
- Low package height of 0.37 mm
- Current gain matching
- · Base-emitter voltage matching
- Application-optimized pinout
- AEC-Q101 qualified

### 3. Applications

- Current mirror
- Differential amplifier

### 4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						•
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-45	V
I <sub>C</sub>	collector current			-	-	-100	mA
I <sub>CM</sub>	peak collector current	$t_p \le 1 \text{ ms}; \text{ single pulse}$		-	-	-200	mA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		200	290	450	
Per device	·				•		•
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE}$ = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		0.95	1	1.05	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[1]	-	-	2	mV

[1] The smaller of the two values is subtracted from the larger value.

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45 V, 100 mA PNP/PNP matched double transistors

### 5. Pinning information

Table 2. F	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	E1	emitter TR1		6 5 4				
2	B1	base TR1						
3	C2	collector TR2						
4	E2	emitter TR2						
5	B2	base TR2		1 2 3				
6	C1	collector TR1		sym018				
7	C1	collector TR1	Transparent top view DFN1010B-6 (SOT1216)					
8	C2	collector TR2	, , , , , , , , , , , , , , , , , , ,					

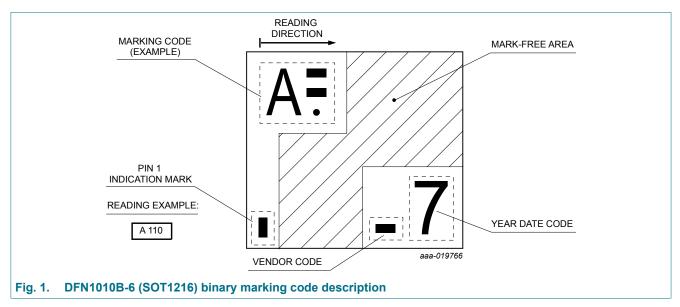
# 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BCM857QAS	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BCM857QAS	C 011



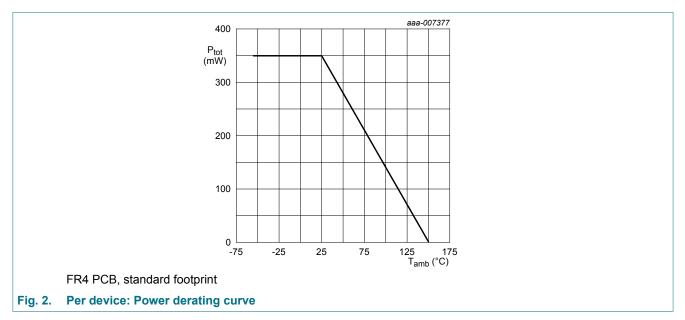
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or					
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-45	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-100	mA
I <sub>CM</sub>	peak collector current	$t_p \le 1 \text{ ms}$ ; single pulse		-	-200	mA
I <sub>BM</sub>	peak base current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
Per device			·			_
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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### 9. Thermal characteristics

Table 6 Thormal characteristics

Table 0. Therm	ai characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transistor					·		
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	544	K/W
Per device		·					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	358	K/W

#### [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

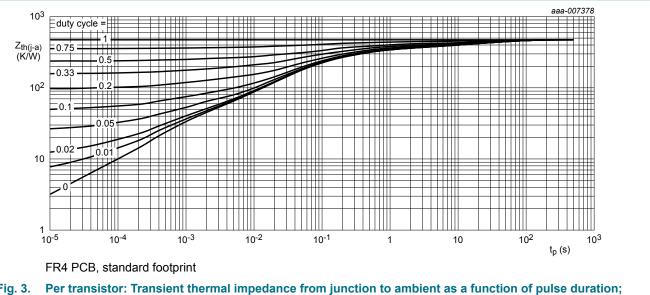


Fig. 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

# **10.** Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or	1					
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A		-50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = -2 mA; I <sub>B</sub> = 0 A		-45	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = -100 μA		-6	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-15	nA
	current	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -10 µA; T <sub>amb</sub> = 25 °C		-	250	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		200	290	450	
V <sub>CEsat</sub> collector-emitte saturation volta	collector-emitter	$I_{C}$ = -10 mA; $I_{B}$ = -0.5 mA; $T_{amb}$ = 25 °C		-	-	-200	mV
	saturation voltage	$I_{C}$ = -100 mA; $I_{B}$ = -5 mA; $T_{amb}$ = 25 °C	[1]	-	-	-400	mV
V <sub>BEsat</sub>	base-emitter saturation	$I_{C}$ = -10 mA; $I_{B}$ = -0.5 mA; $T_{amb}$ = 25 °C	[2]	-	-760	-	mV
	voltage	$I_{C}$ = -100 mA; $I_{B}$ = -5 mA; $T_{amb}$ = 25 °C	[2]	-	-900	-	mV
V <sub>BE</sub>	base-emitter voltage	$V_{CE}$ = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C	[3]	-600	-660	-725	mV
		$V_{CE}$ = -5 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C	[3]	-	-710	-820	mV
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	4	pF
C <sub>e</sub>	emitter capacitance	V <sub>EB</sub> = -0.5 V; I <sub>C</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	10	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		100	175	-	MHz
Per device							
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE}$ = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		0.95	1	1.05	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[4]	-	-	2	mV

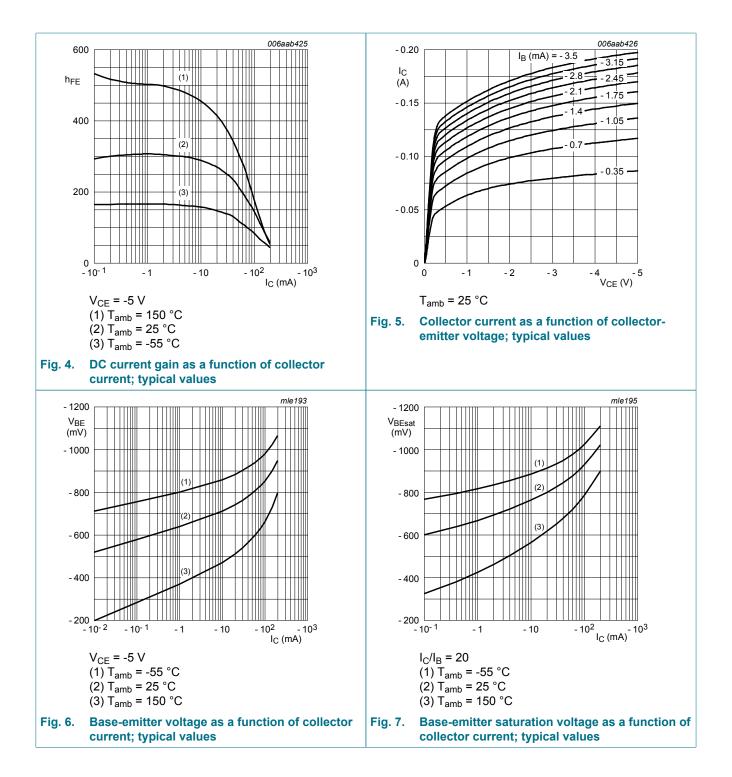
[1]

Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02$  $V_{BEsat}$  decreases by about 1.7 mV/K with increasing temperature.  $V_{BE}$  decreases by about 2 mV/K with increasing temperature. The smaller of the two values is subtracted from the larger value. [2]

[3] [4]

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### 45 V, 100 mA PNP/PNP matched double transistors

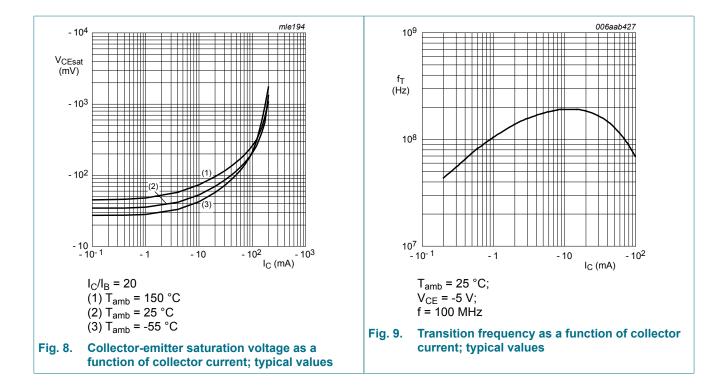


**Product data sheet** 

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# BCM857QAS

### 45 V, 100 mA PNP/PNP matched double transistors

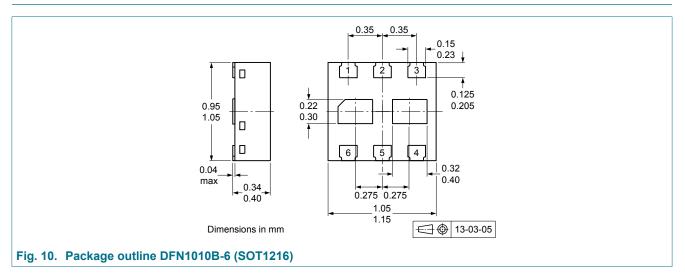


### **11. Test information**

### **Quality information**

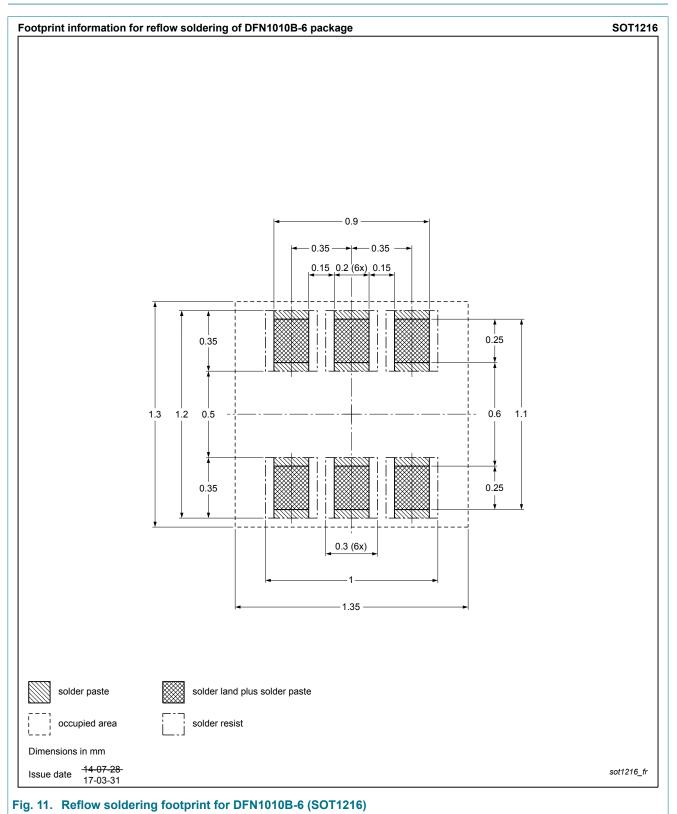
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 12. Package outline



45 V, 100 mA PNP/PNP matched double transistors

### 13. Soldering



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# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BCM857QAS v.1	20180424	Product data sheet	-	-		

#### 45 V, 100 mA PNP/PNP matched double transistors

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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24 April 2018

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